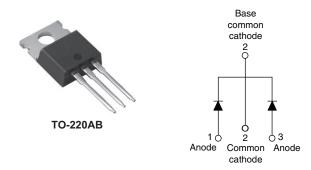


VS-63CTQ100GPbF, VS-63CTQ100G-N3

Vishay Semiconductors

Schottky Rectifier, 2 x 30 A



PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 30 A				
V _R	100 V				
V _F at I _F	0.69 V				
I _{RM} max.	20 mA at 125 °C				
T _J max.	175 °C				
Diode variation	Common cathode				
E _{AS}	11.25 mJ				

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



RoHS

- Strength and moisture resistance
 Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS VALUES						
I _{F(AV)}	Rectangular waveform (per device)	60	А				
V _{RRM}		100	V				
I _{FRM}	$T_{\rm C} = 139 \ ^{\circ}{\rm C}$ (per leg)	60	А				
I _{FSM}	t _p = 5 μs sine	t _p = 5 μs sine 1500					
V _F	30 A _{pk} , T _J = 125 °C	0.69	V				
TJ	Range	- 65 to 175	°C				

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-63CTQ100GPbF	VS-63CTQ100G-N3	UNITS			
Maximum DC reverse voltage	V _R	100	100	V			
Maximum working peak reverse voltage	V _{RWM}	100	100	v			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST COND	ITIONS	VALUES	UNITS	
Maximum average per leg			50 % duty cycle at T _C = 139 °C	rootangular wayoform	30		
forward current	per device	I _{F(AV)}	30% duty cycle at $1^\circ_{\rm C} = 139$ C	, rectangular wavelonn	60		
Peak repetitive forward current per leg		I _{FRM}	Rated V_R , square wave, 20 kHz, T_C = 140 °C		60	А	
Maximum peak one cycle non-repetitive surge current per leg		I =0.1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1500		
		IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	300		
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 0.75 A, L = 40 mH		11.25	mJ	
Repetitive avalanche current pe	er leg	I _{AR}	Current decaying linearly to zero Frequency limited by T_J maxim		0.75	А	

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS	
Maximum forward voltage drop		30 A	T _{.1} = 25 °C	0.78	0.82		
	V _{FM} ⁽¹⁾	60 A	1j=25 C	0.94	1.0	V	
	V FM (*)	30 A	T 105 %O	0.64	0.69		
		60 A	T _J = 125 °C	0.78	0.83		
Maximum instantaneous reverse current	I _{RM}	T _J = 25 °C	$V_{\rm B} = Rated V_{\rm B}$	0.02	0.3	mA	
		T _J = 125 °C	VR - naleu VR	11	20	IIIA	
Maximum junction capacitance	CT	V_{R} = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 $^{\circ}\text{C}$		11	00	pF	
Typical series inductance	L _S	Measured from top of terminal to mounting plane		ing plane 8.0		nH	
Maximum voltage rate of change	dV/dt	Rated V _R	10	000	V/µs		

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	R SYMBOL TEST CONDITIONS					
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65 to 175	°C		
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.2	°C/W		
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	0/11		
Approximate weight			2	g		
Approximate weight			0.07	oz.		
Mounting torgue minimur	ı	Non-lubricated threads	6 (5)	kgf ⋅ cm		
maximur	ı	Non-Indicated inteads	12 (10)	(lbf · in)		
Marking device		Case style TO-220AB	63CTC	0100G		



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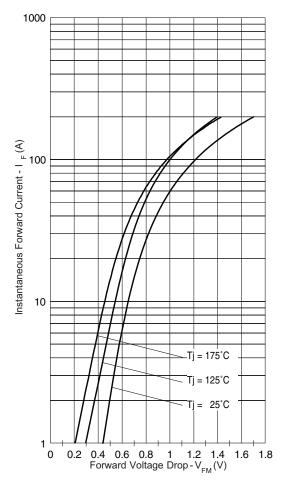


Fig. 1 - Maximum Forward Voltage Drop Characteristics

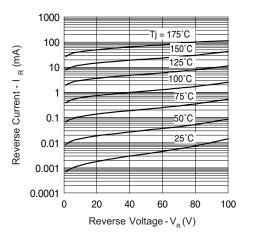


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

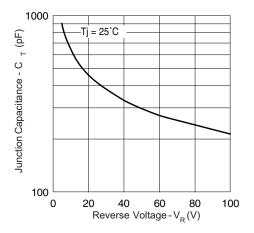
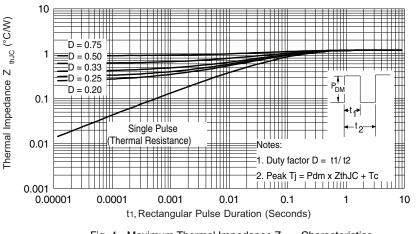


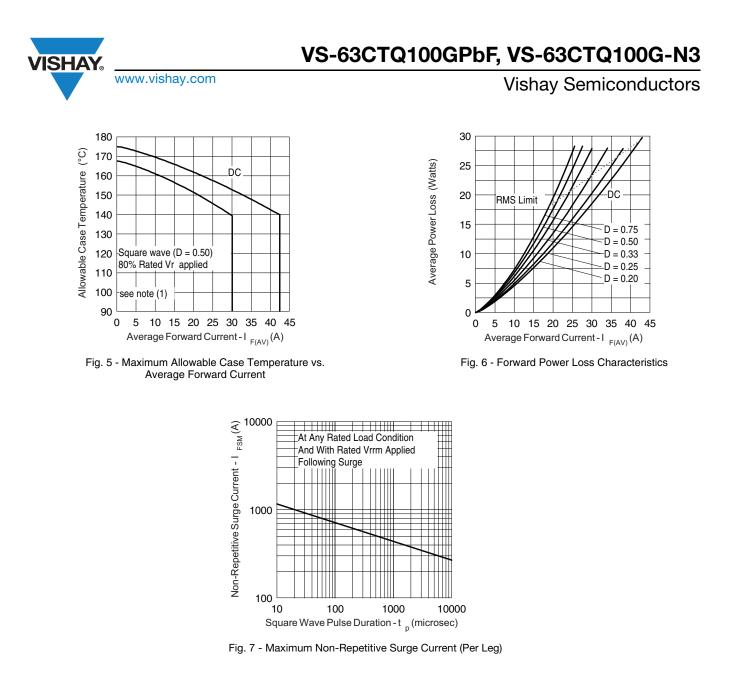
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





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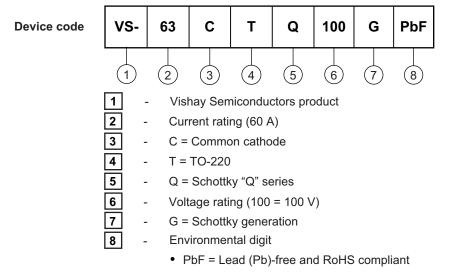
Note



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ORDERING INFORMATION TABLE



• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-63CTQ100GPbF	50	1000	Antistatic plastic tube				
VS-63CTQ100G-N3	50	1000	Antistatic plastic tube				

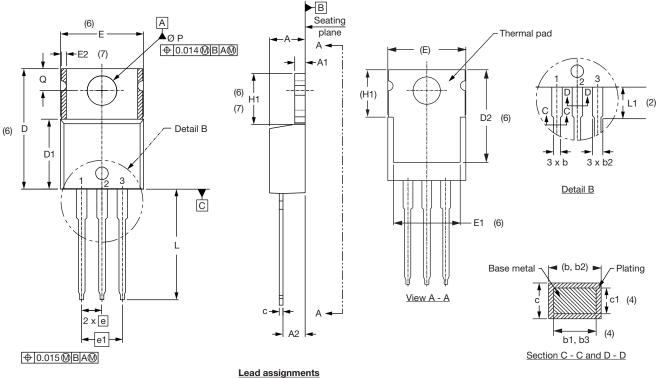
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95222					
Part marking information	TO-220AB PbF	www.vishay.com/doc?95225			
	TO-220AB -N3	www.vishay.com/doc?95028			

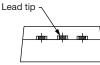


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TO-220AB

DIMENSIONS in millimeters and inches





_ead	assi	gnr	ne	nts
		-		

Diodes

3. - Anode

1. - Anode/open 2. - Cathode

SYMBOL	MILLIN	IETERS	INC	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- ⁽³⁾ Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed $0.127 \text{ mm} (0.005^{\circ})$ per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left(4\right) }$ Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

SYMBOL	MILLIMETERS INCHES		HES	NOTES	
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° t	o 93°	
	•		•		•

Conforms to JEDEC outline TO-220AB

- $^{(7)}$ Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- Outline conforms to JEDEC TO-220, except A2 (maximum) and (8) D2 (minimum) where dimensions are derived from the actual package outline

Document Number: 95222 Revision: 08-Mar-11

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